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Large-area synthesis of highly crystalline WSe₂ monolayers and device applications

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820	Circular Dichroism Control of Tungsten Diselenide (WSe ₂) Atomic Layers with Plasmonic Metamolecules.		
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818	Point Defects and Localized Excitons in 2D WSe ₂ .		
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816	Three-Dimensional Resonant Exciton in Monolayer Tungsten Diselenide Actuated by SpinOrbit Coupling.		
815	Book review: Bloody Nasty People. 2013 , 60, 445-447		
814	High-performance photocurrent generation from two-dimensional WS ₂ field-effect transistors. 2014 , 104, 193113		72
813	Optical properties of monolayer transition metal dichalcogenides probed by spectroscopic ellipsometry. 2014 , 105, 201905		250
812	Fast visible-light phototransistor using CVD-synthesized large-area bilayer WSe ₂ . 2014 ,		
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810	Wet chemical thinning of molybdenum disulfide down to its monolayer. 2014 , 2, 092509		24
809	Two-dimensional Fermi surfaces in Kondo insulator SmB ₆ 2014 , 346, 1208-12		202
808	Ultrafast generation of pseudo-magnetic field for valley excitons in WSe ₂ monolayers. 2014 , 346, 1205-8		192
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806	Vapor-transport growth of high optical quality WSe ₂ monolayers a. 2014 , 2, 101101		48

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